

Data sheet acquired from Harris Semiconductor SCHS099B – Revised January 2003

# CD40109B Types

# CMOS Quad Low-to-High Voltage Level Shifter Fe

High-Voltage Types (20-Volt Rating)

## CD401098 contains four low-to-high-voltage level-shifting circuits. Each circuit will shift a low-voltage digital-logic input signal (A, B, C, D) with logical 1 = V<sub>CC</sub> and logical 0 = V<sub>SS</sub> to a higher-voltage out-put signal (E, F, G, H) with logical 1 = V<sub>DD</sub> and logical 0 = V<sub>SS</sub>.

The CD40109, unlike other low-to-high level-shifting circuits, does not require the presence of the high-voltage supply (VDD) before the application of either the low-voltage supply (V<sub>CC</sub>) or the input signals. There are no restrictions on the sequence of application of VDD, VCC, or the input signals. In addition, with one exception there are no restrictions on the relative magnitudes of the supply voltages or input signals within the device maximum ratings, provided that the input signal swings between VSS and at least 0.7 VCC;  $V_{CC}$  may exceed  $V_{DD}$ , and input signals may exceed  $V_{CC}$  and  $V_{DD}$ . When operated in the mode  $V_{CC} > V_{DD}$ , the CD40109 will operate as a high-to-low level-shifter.

The CD40109 also features individual threestate output capability. A low level on any of the separately enabled three-state output controls produces a high-impedance-state in the corresponding output.

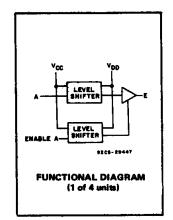
The CD40109B-Series types are supplied in 16-lead ceramic dual-in-line packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (NSR suffix), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

#### Applications:

- High-or-low level-shifting with three-state outputs for unidirectional or bidirectional bussing
- Isolation of logic subsystems using separate power supplies from supply sequencing, supply loss and supply regulation considerations

#### Features:

- Independence of power supply sequence considerations—V<sub>CC</sub> can exceed V<sub>DD</sub>, input signals can exceed both V<sub>CC</sub> and V<sub>DD</sub>
- Up and down level-shifting capability
- Three-state outputs with separate enable controls
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range)
  - = 1 V at  $V_{CC}$  = 5 V,  $V_{DD}$  = 10 V
  - = 2 V at V<sub>CC</sub> = 10 V, V<sub>DD</sub> = 15 V
- 5-V, 10-V, and 15-V parametric ratings
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of "B" Series CMOS Devices"



#### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

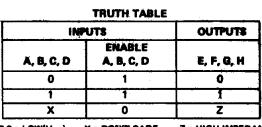
0114 D 4 077 010710	Lii	1 1011 70		
CHARACTERISTIC	MIN.	MAX.	UNITS	
Supply-Voltage Range (For TA =				
Full Package-Temperature Range)	3	18	V.	

#### MAXIMUM RATINGS, Absolute-Maximum Values:

LEAD TEMPERATURE (DURING SOLDERING):

DC SUPPLY-VOLTAGE RANGE, (V <sub>DD</sub> )
Voltages referenced to VSS Terminal)0.5V to +20V
OUTPUT VOLTAGE RANGE, ALL OUTPUTS0.5 V to V <sub>DD</sub> +0.5 V
DC INPUT CURRENT, ANY ONE INPUT ±10mA
POWER DISSIPATION PER PACKAGE (PD):
For T <sub>A</sub> = -55°C to +100°C
For T <sub>A</sub> = +100°C to +125°C Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55°C to +125°C
STORAGE TEMPERATURE RANGE (Tato)65°C to +150°C

At distance 1/16  $\pm$  1/32 inch (1.59  $\pm$  0.79mm) from case for 10s max ...... +265°C



LOGIC 0 - LOW(V<sub>SS</sub>) X - DON'T CARE Z - HIGH IMPEDANCE LOGIC 1 - V<sub>CC</sub> at INPUTS and V<sub>DD</sub> at OUTPUTS

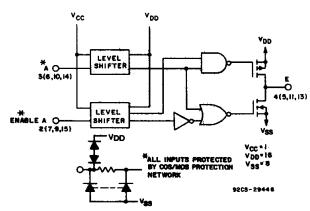


Fig.1 - CD40109B logic diagram (1 of 4 units).

## STATIC ELECTRICAL CHARACTERISTICS

CHARACTER	CONDITIONS			LIMITS AT INDICATED TE							UNITS
ISTIC	Vo (V)	VIN (V)	V <sub>DD</sub> (V)	-55	-40	+85	+125	Min.	+25 Typ.	Max.	
Quiescent Device	_	0,5	5	1	1	30	30		0.02	1	
Current,	- 1	0,10	10	2	2	60	60		0.02	2	١ .
IDD Max.	- 1	0,15	15	4	- 4	120	120	-	0.02	4	μΑ
	_	0,20	20	20	20	600 .	600	<del></del>	0.04	20	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1		
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		100
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	3 4	6.8		
Output High	4.6	.0,5	5 .	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source)	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	<sub>ှ</sub> -3.2	-	
Current,	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	
IOH Min.	13.5	0,15	15	-4.2	-4	-2.8	2.4	-3.4	-6.8	. –	
Output Voltage:	_	0,5	5	,	0	.05		_	0	0.05	
Low-Level,	_	0,10	10		0	.05		_	0	0.05	
VOL Max.		0,15	15	0.05					0	0.05	V
Output Voltage:		0,5	5		4.95				. 5	-	"
High-Level,	· -	0,10	10		. 9	95		9.95	10		
VOH Min.		0,15	15		14	:95		14.95	15	_	1 :
Input Current IIN Max.		0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μΑ
3-State Output Leakage Current IOUT Max.		0,18	18	±0.4	±0.4	±12	±12	: : * * <del>-</del>	±10 <sup>-4</sup>	±0.4	μΑ
	35	Vcc (V)	V <sub>DD</sub> (V)	:		y 1		n i e			
Input Low Voltage,	1,9	5	10			.5			_	1.5	
VIL Max.	1.5, 13.5	10	15			3		_	_	3	
Input High	1,9	5	10			3.5	,	3.5		-	\ \
Voltage, VIH Min.	1.5,13.5	10	15			7 		7	19 <u>14 </u> 19 1 4 1 1	_	

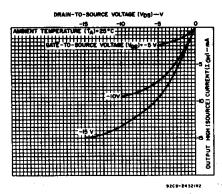


Fig.5 - Minimum output high (source)current characteristics.

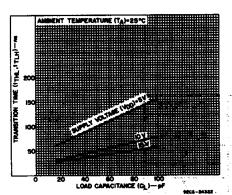


Fig.6 - Typical transition time as a function of load capacitance.

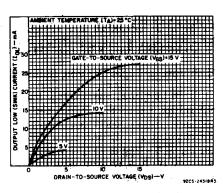


Fig.2 - Typical output low (sink) current characteristics.

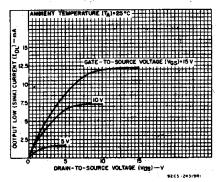


Fig.3 – Minimum output low (sink) current characteristics.

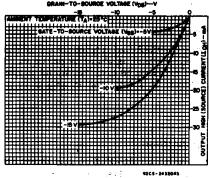


Fig.4 - Typical output high (source).

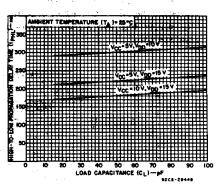


Fig.7 - Typical high-to-low propagation delay time as a function of load capacitance.

## CD40109B Types

# DYNAMIC ELECTRICAL CHARACTERISTICS at T $_A$ = 25°C, Input t $_r$ , t $_f$ = 20 ns, C $_L$ = 50 pF, R $_L$ = 200 k $\Omega$ unless otherwise specified

	SHIFTING	Vcc	C VDD LIMITS				
CHARACTERISTIC	MODE	(V)	(V)	Тур.	Max.	UNITS	
Propagation Delay - Data Input	-	5	10	300	600		
to Output:	L-H	5	15	220	440		
Mah sa Laur Laur La		10	15	180	360		
High-to-Low Level, tpHL		10	5	250	500	ns	
	H-L	15	5	250	500		
		15	10	120	240		
		5	10	130	260		
	L-H	5	15	120	240		
Low-to-High Level, tpLH		10	15	70	140		
Edw-to-riight cever, tPLH		10	5	230	460	ns	
	H-L	15	5	230	460		
		15	10	80	160		
3-State Disable Delay:		5	10	60	120		
R <sub>L</sub> = 1 kΩ	L-H	5	15	75	150		
Output High to High		10	15	35	70	ns	
Impedance, tpHZ		10	5	200	400	''\$	
	H-L	15	5	200	400		
		15	10	40	80		
·	. L-H	5	10	370	740	ns	
Output Low to High		5	15	300	600		
Impedance, tp_Z		10	15	250	500		
#		10	5	250	500		
:	H-L	15	5	250	500		
		15	10	130	260		
,		5	10	320	640		
High Impedance to	L-H	5	15	230	460	ns	
Output High, tpZH		10	15	180	360		
		10	5	300	600		
	H-L	15 15	5 10	300 130	600 260		
		5	10				
	L-H	5 5	15	100 80	200 160		
High Impedance to	<u>.</u> .,	10	15	40	80	ns	
Output Low, tpZL		10	5	200	400		
	H-L	15	5	200	400		
	,,	15	10	40	80		
7 Turkeya (199 <b>-1994)</b>	要学生	• 25·	¥ 10	50	100		
	L-H	1 5	15	40	80		
2 Jan 17 Jan 18		10.	15	40	80		
Transition Time, TTHL, TTLH	1.4	10 🐗	5	100	200	ns	
	H-L	15	- 5	100	200		
		15	10	50	100		
Input Capacitance, C		Any	Input	5	7.5	ρF	
	IT.	14		L			

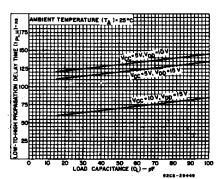


Fig.8 — Typical low-to-high propagation delay time as a function of load capacitance.

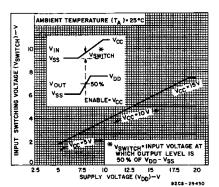


Fig.9 — Typical input switching as a function of high-level supply voltage.

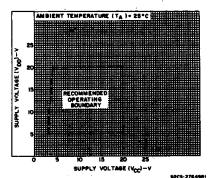


Fig. 10 — High-level supply voltage vs. low-level supply voltage.

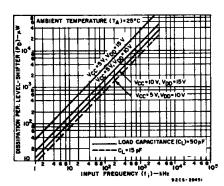


Fig.11 — Typical dynamic power dissipation as a function of input frequency.

## CD40109B Types

#### **TEST CIRCUITS**

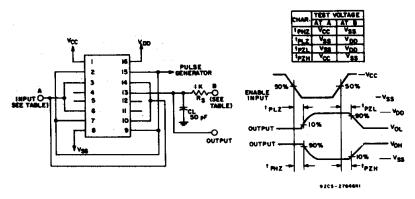


Fig. 12 - Output enable delay times test circuit and waveforms.

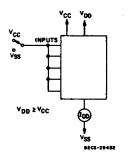


Fig. 13 - Quiescent device current.

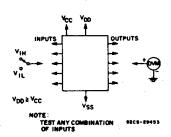


Fig. 14 - Input voltage.

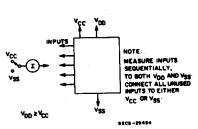


Fig. 15 - input current.

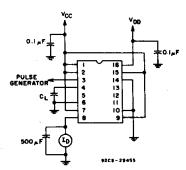
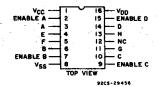
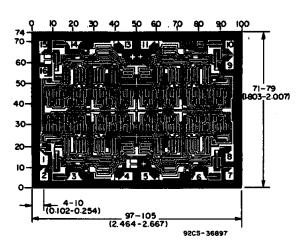


Fig. 16 - Dynamic power dissipation test circuit.



#### CD40109B TERMINAL ASSIGNMENT

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils ( $10^{-3}$  inch).



Dimensions and pad layout for CD401098H.





i.com 18-Jul-2006

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
CD40109BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD40109BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD40109BF	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD40109BF3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD40109BK3	OBSOLETE	CFP	WR	16		TBD	Call TI	Call TI
CD40109BNSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40109BNSRE4	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40109BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40109BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40109BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD40109BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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## 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## PW (R-PDSO-G\*\*)

#### 14 PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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